Physical Metallurgy Principles SI Version



Chapter Five: Dislocations and Plastic Deformations

PHYSICAL METALLURGY PRINCIPLES

REZA ABBASCHIAN LARA ABBASCHIAN ROBERT E. REED-HILL Connected with the relation of dislocations to plastic deformation

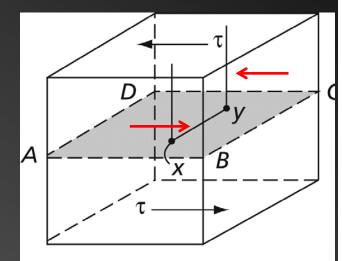
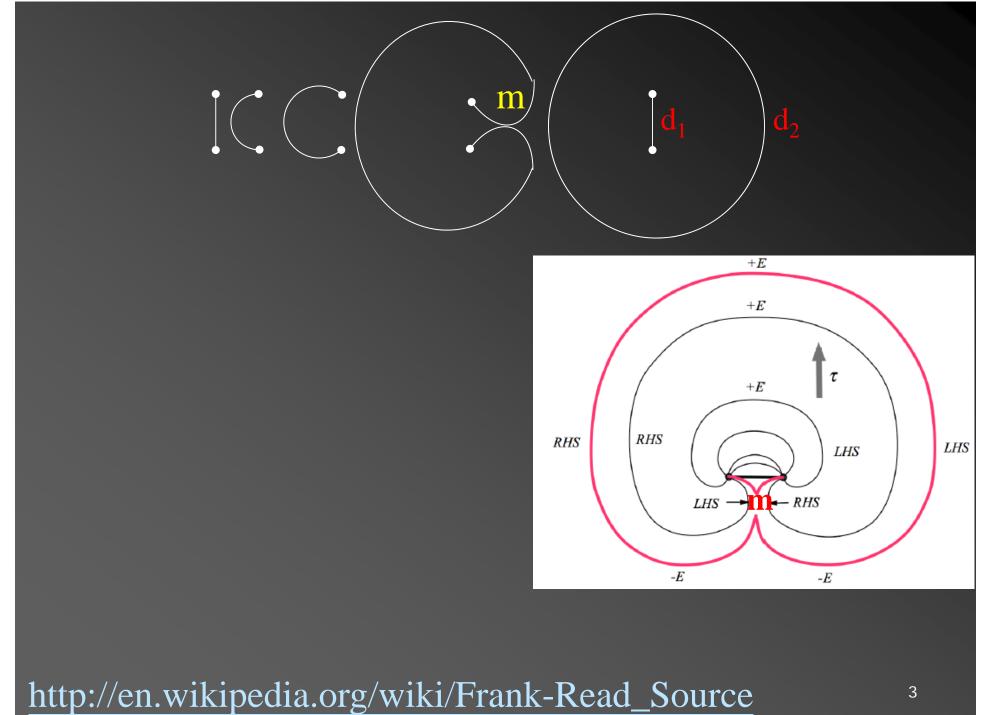


FIG. 5.1 Frank-Read source. The dislocation segment *xy* may move in plane *ABCD* under the applied stress. Its ends, *x* and *y*, however, are fixed



Elementary Dislocation Theory, J. Weertman and J. R. Weertman, P. 125. 4

5.2 Nucleation of Dislocations

• Dislocations can also be formed without the aid of Frank-Read or similar sources.

• Metal is not suitable for the dislocation nucleation studies

Low-angle grain boundaries

Newly formed
(large squares)
(r.t.)Grown-in
(high temp.)
(network dislocations
closely spaced smaller
pits)

FIG. 5.3 The large square etched pits in horizontal rows correspond to dislocations formed in LiF at room temperature, while the smaller, closely spaced pits lying in curved rows were grown into the crystal when it was manufactured (Gilman, J. J., and Johnson, W. G., *Dislocations and Mechanical Properties of Crystals*, p. 116, John Wiley and Sons, Inc., New York, 1957. Used by permission of the author.)

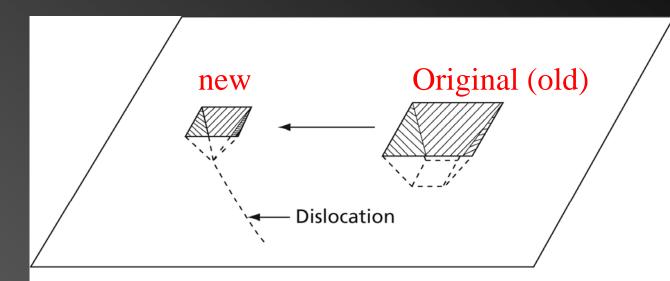
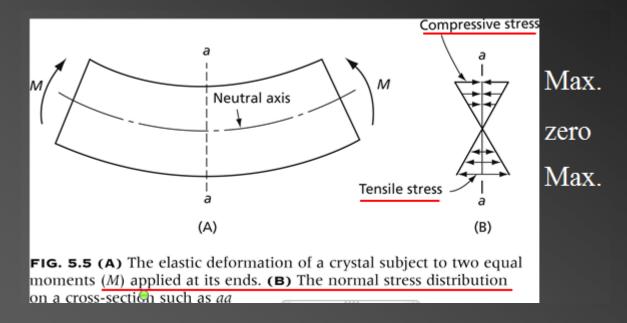


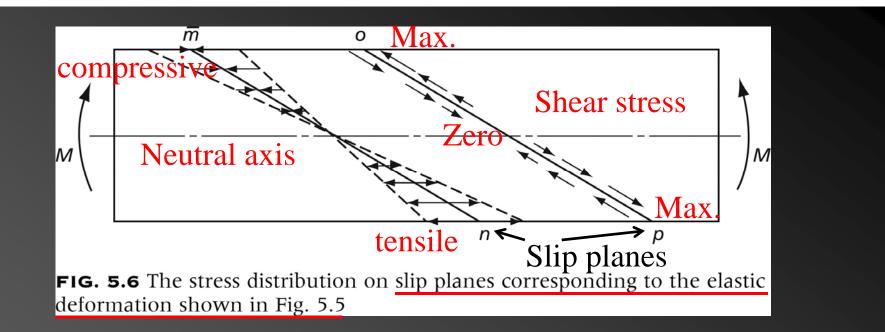
FIG. 5.4 Dislocation movement in LiF as revealed by repeated etching (Reprinted with permission from J.J. Gilman and W.G. Johnson, *Journal of Applied Physics*, Vol. 30, Issue 2, Page 129, Copyright 1959, American Institute of Physics)

5.3 Bend Gliding:



• The stress distribution: $\sigma_x = \frac{My}{I}$

M: bending moment y: vertical distance I: moment of inertia $(= \pi r^4/4;$ for a circular rod)



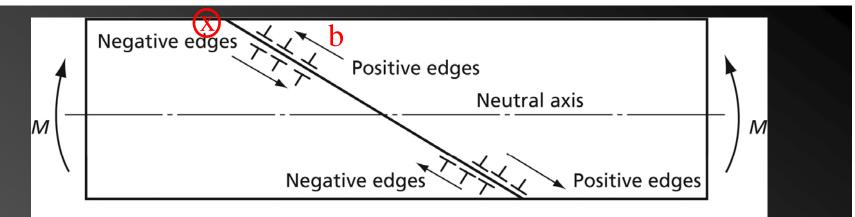


FIG. 5.7 The effect of the stress distribution on the movement of dislocations. Positive-edge components move toward the surface; negative edges toward the neutral axis

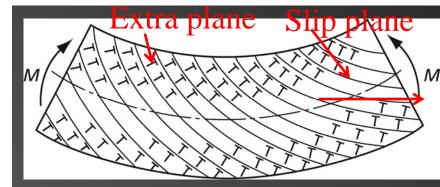
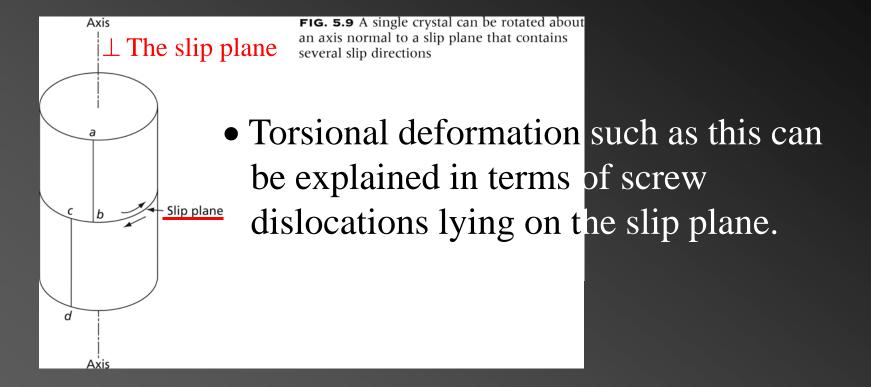


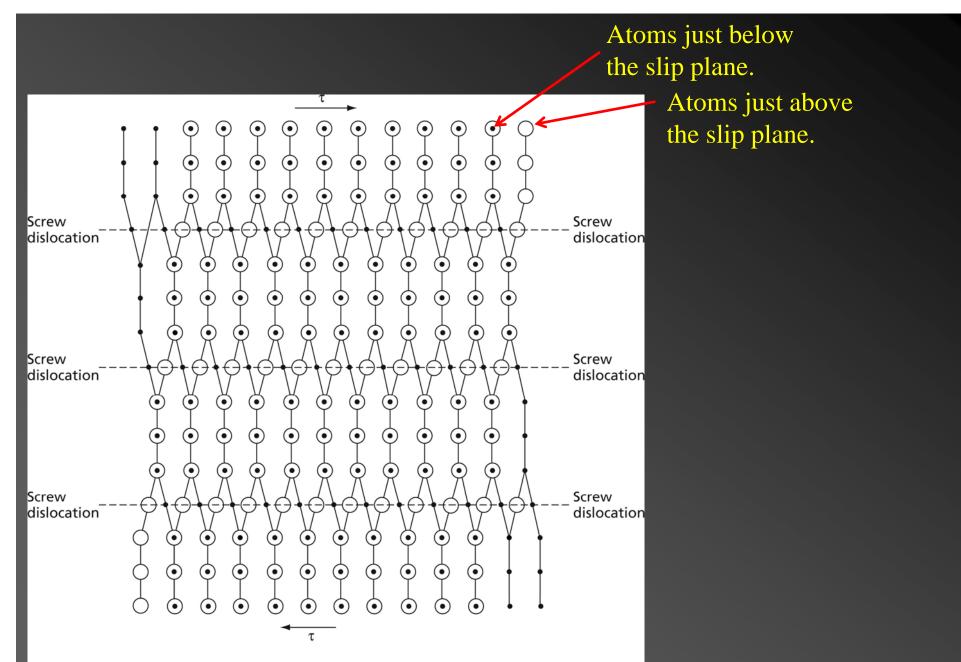
FIG. 5.8 Distribution of the excess edge dislocations in a plastically bent crystal MNarrow section surrounding the axis: free of dislocations

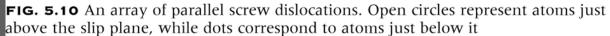
=> under moderate stresses (not plastic)

 \Rightarrow will not be stressed above the elastic limit

5.4 Rotational Slip:







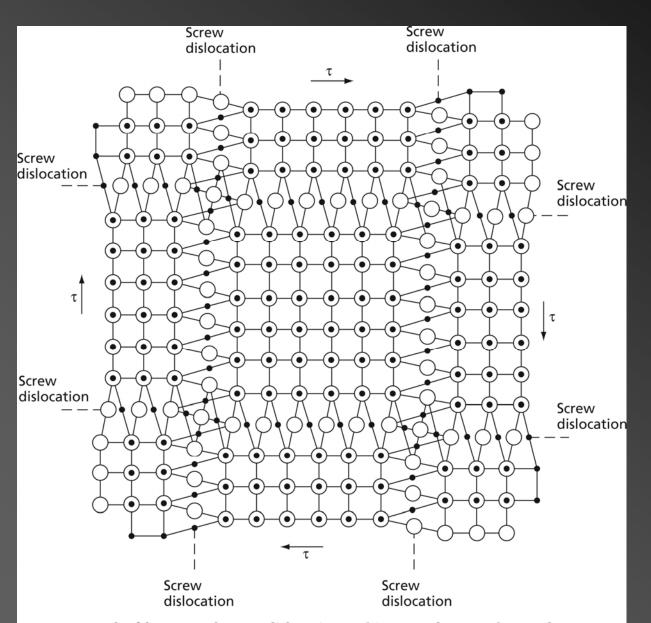
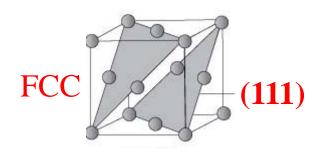
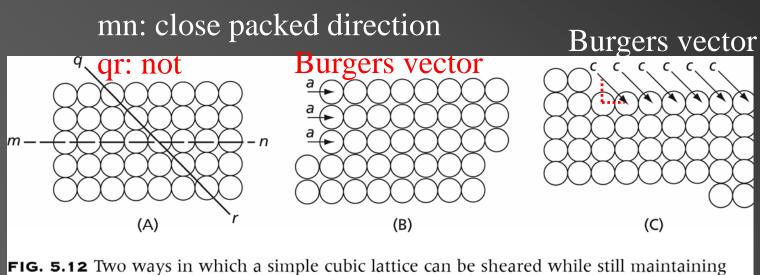


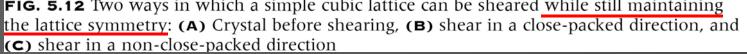
FIG. 5.11 A double array of screw dislocations. This array does not have a longrange strain field; open circles show atoms above the slip plane, while dots represent those below the plane

5.5 Slip Planes and Slip Directions

• Experimental fact: slip occurs preferentially on planes of **high atomic density**







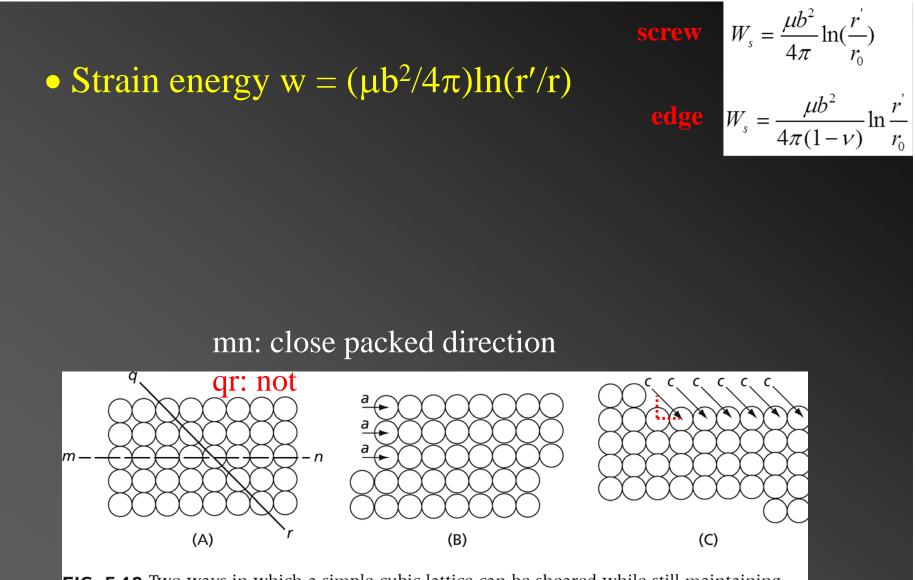
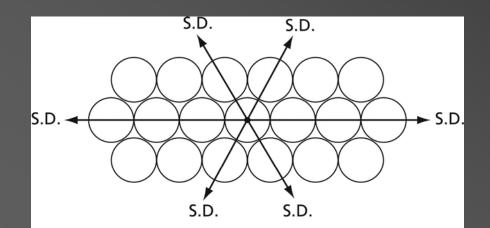
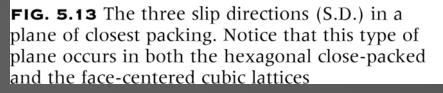
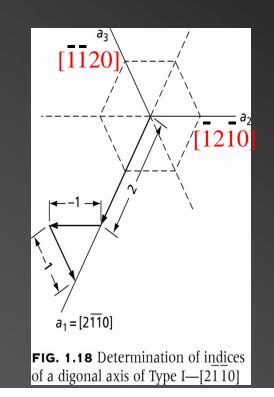


FIG. 5.12 Two ways in which a simple cubic lattice can be sheared while still maintaining the lattice symmetry: **(A)** Crystal before shearing, **(B)** shear in a close-packed direction, and **(C)** shear in a non-close-packed direction

5.6 Slip Systems:







5.7 Critical Resolved Shear Stress (yield stress)
4. Slip divergence of the specimen axis

$$A_n = A_{sp} \cos \theta$$

 A_n : cross section area perpendicular to the specimen axis
 A_{sp} : the slip plane
 A_{sp} : the slip plane

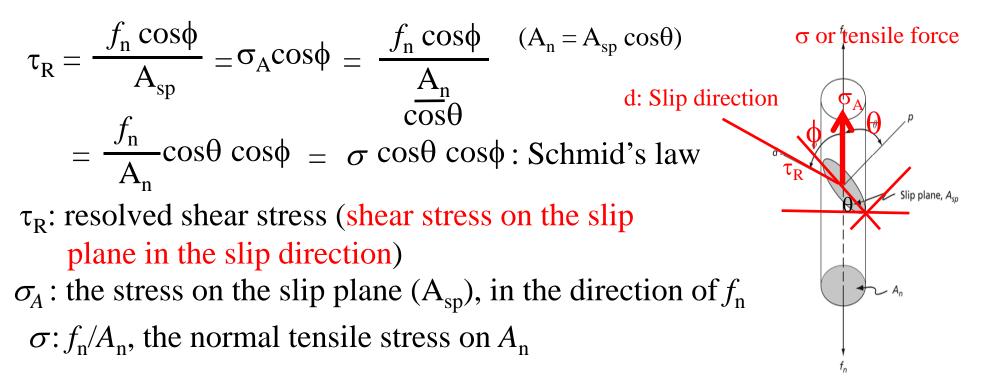
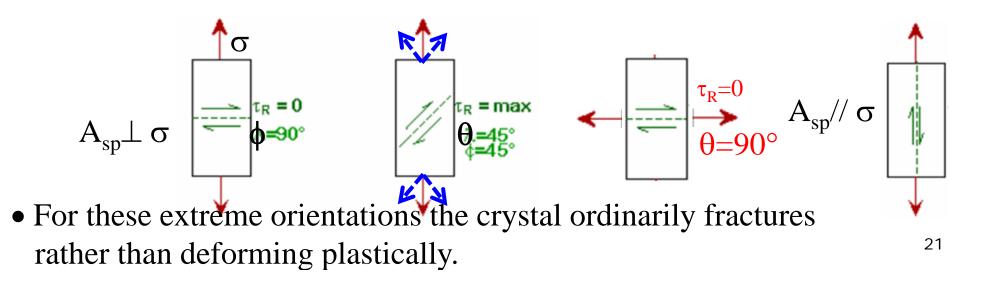


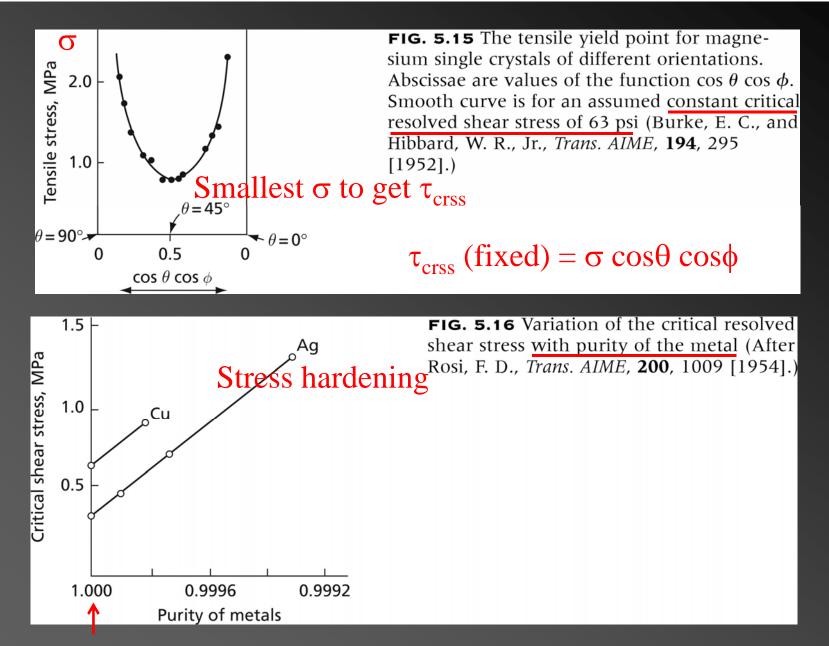
FIG. 5.14 A figure for the determination of the critical resolved shear stress equation



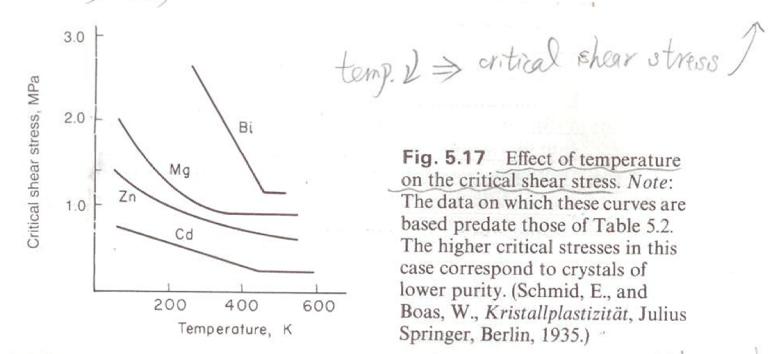
• Maximum shear stress (0.5 σ) occurs when $\phi = \theta = 45^{\circ}$.

• if $\tau_R > \tau_{crss}$ (critical resolved shear stress) => plastic deformation by slip.

http://www.doitpoms.ac.uk/tlplib/slip/slip_geometry.php



Totally pure metals: very high τ_R



GI 0 4505

but very hist.

• Strengthening of metallic materials:

• There are five main strengthening mechanisms for metals

1. Work hardening

⇒ such as beating a red-hot piece of metal on anvil, has been used for centuries by blacksmiths to introduce dislocations into materials, increasing their yield strengths.

2. Solid Solution Strengthening/Alloying (impurity)

3. Precipitation Hardening (impurity)

4. Grain Boundary (Grain Size) Strengthening

5. Transformation Hardening

5.8 Slip On Equivalent Slip Systems

5.9 The Dislocation Density

• Dislocation density (ρ) :

by estimating the length of the dislocation line (cm/cm³)
 by the number of dislocation etch pits (#/cm²).

5.10 Slip Systems in Different Crystal Forms

Slip Systems in FCC:

close packed direction: <110>; four closed packed planes (octahedral plane): (111), (-111), (1-11), (11-1); Each octahedral plane have three slip directions
 => 4 × 3 = 12 slip systems.

• If the slip planes intersecting each other, or mutual interference of dislocations gliding on intersecting slip planes,

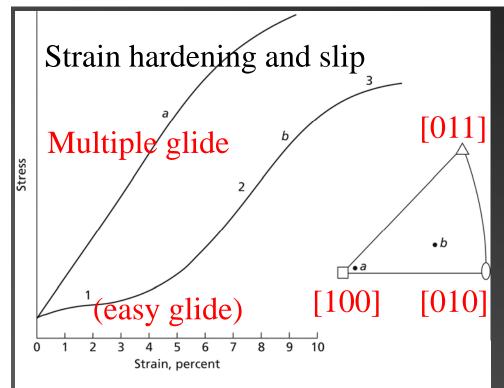


FIG. 5.17 Typical <u>face-centered cubic single crystal</u> stress-strain curves. Curve *a* corresponds to deformation by multiple glide from start of deformation; curve *b* corresponds to multiple glide after a period of single slip (easy glide). Crystal orientations are shown in the stereographic triangle

TABLE 5.3 The *c/a* Ratio for Hexagonal Metals.

Meta	al c/a	
Cd	1.886	
Zn	1.856	
Mg	1.624	
Zr	1.590	
Ti	1.588	
Be	1.586	32

\Rightarrow Any plane contains a close-packed <111> direction can act as a slip plane.

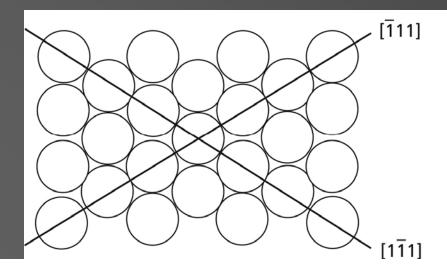
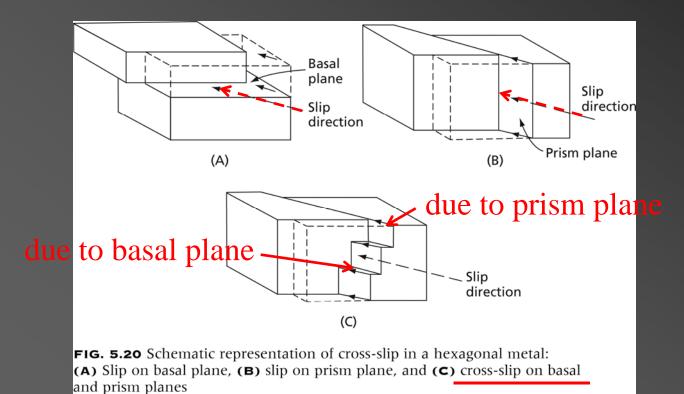
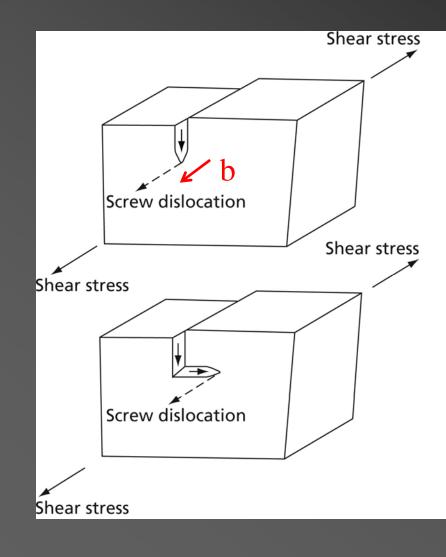


FIG. 5.19 The (110) plane of the body-centered cubic lattice

5.11 Cross-Slip (different from dislocation intersection)





b: Burgers vector

• Screw dislocations move in different planes

FIG. 5.22 Motion of a screw dislocation during cross-slip. In the upper figure the dislocation is moving in a vertical plane, while in the lower figure it has shifted its slip plane so that it moves horizontally

Prism plane {10-10}

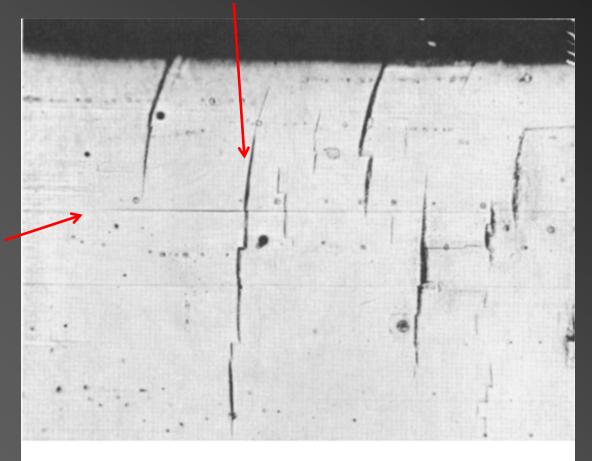


FIG. 5.21 Cross-slip in magnesium. The vertical slip plane traces correspond to the $\{1010\}$ prism plane, whereas the horizontal slip plane traces correspond to the basal plane (0002). 290 × (Reed-Hill, R. E., and Robertson, W. D., *Trans. AIME*, **209** 496 [1957].)

basal plane (0001)

• In many HCP metals, no cross-slip can occur because the slip planes are parallel (not intersecting).

• A single crystal of Mg (HCP) can be stretched into a ribbon-like shape four ~ six times its original length.

• However, polycrystalline Mg shows limited ductilities (brittle).

5.12 Slip Bands:

Etch pits

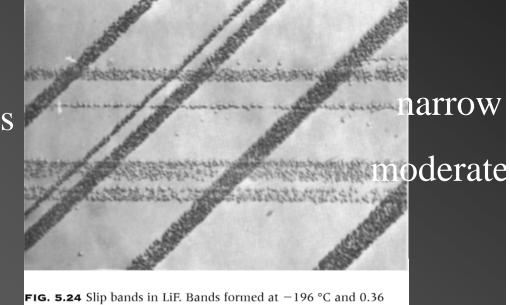
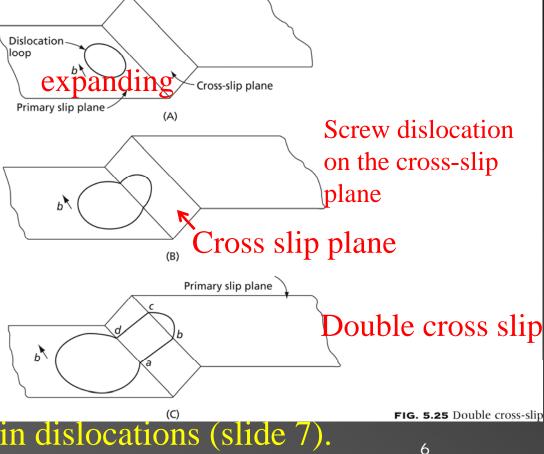


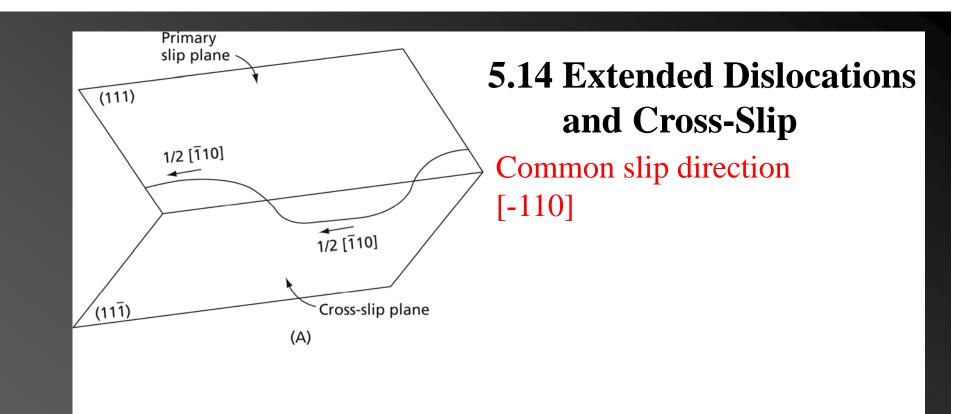
FIG. 5.24 Slip bands in LIP. Bands formed at -196 °C and 0.36 percent strain (Reprinted with permission from J.J. Gilman and W.G. Johnson, *Journal of Applied Physics*, Vol. 30, Issue 2, Page 129, Copyright 1959, American Institute of Physics)

5.13 Double Cross-Slip:

- bc: dislocations can be created on the new slip plane.
- Similar to Frank-Read source.
- These freshly created dislocations will not have enough time to become pinned by impurity atoms.

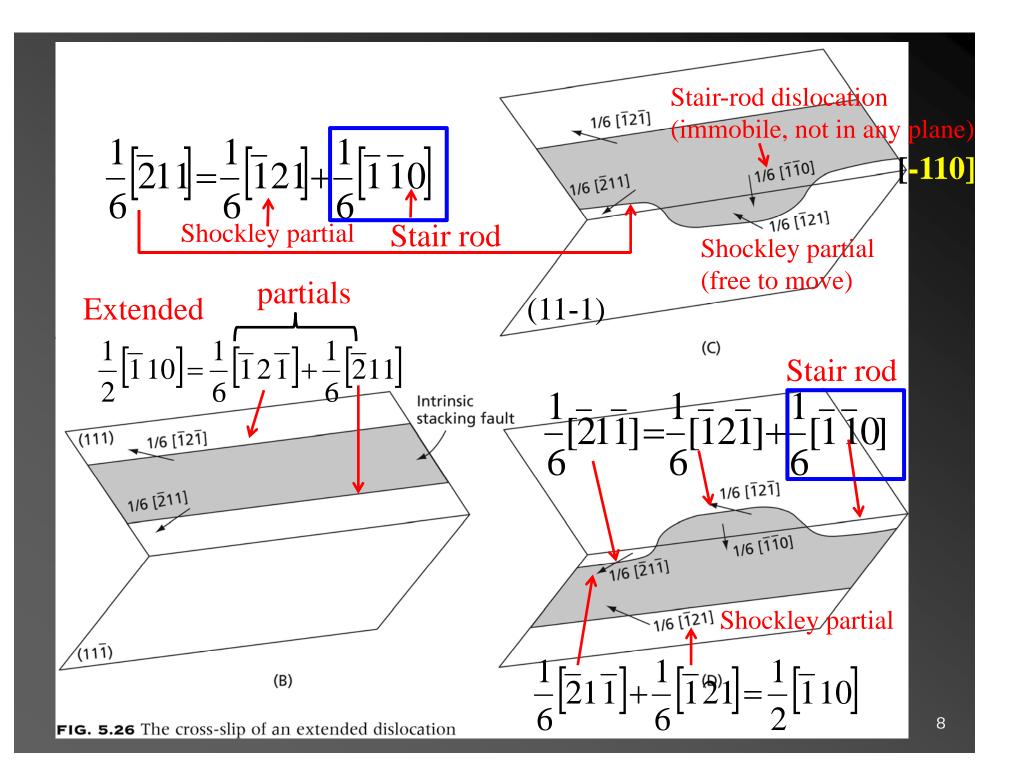


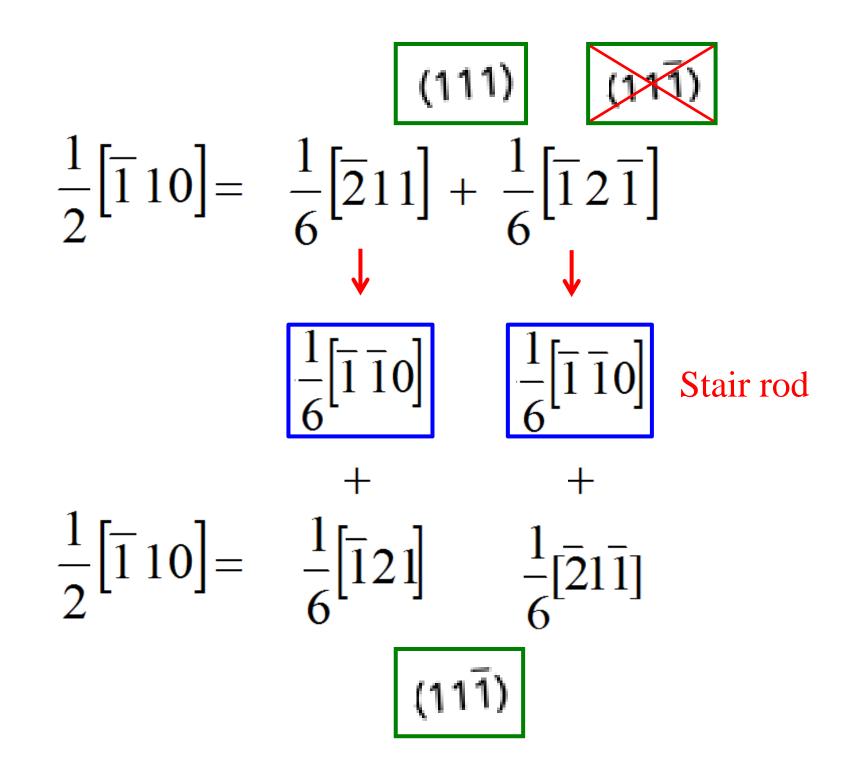




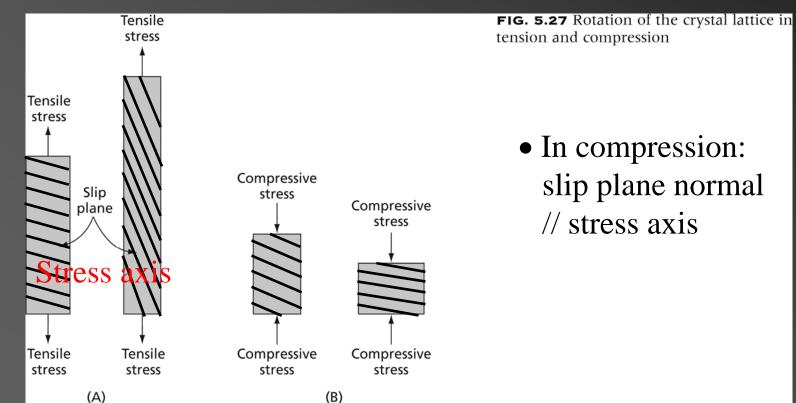
 $\frac{1}{2}\left[\overline{1}10\right] = \frac{1}{6}\left[\overline{1}2\overline{1}\right] + \frac{1}{6}\left[\overline{2}11\right]$

7





5.15 Crystal Structure Rotation during Tensile and **Compressive Deformation**



1

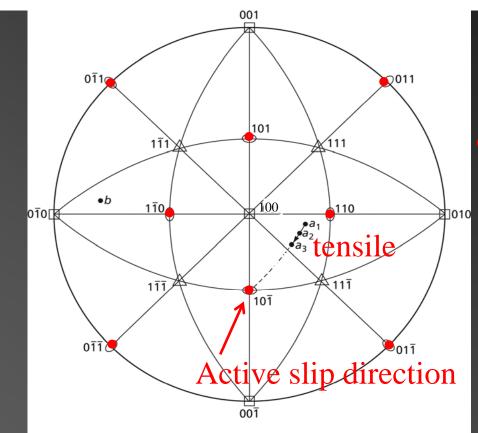


FIG. 5.28 In tension the lattice rotation is equivalent to a rotation of the stress axis (*a*) toward the slip direction. This stereographic projection shows this rotation in a face-centered cubic crystal

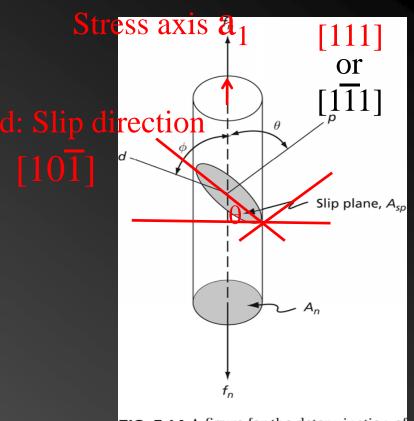
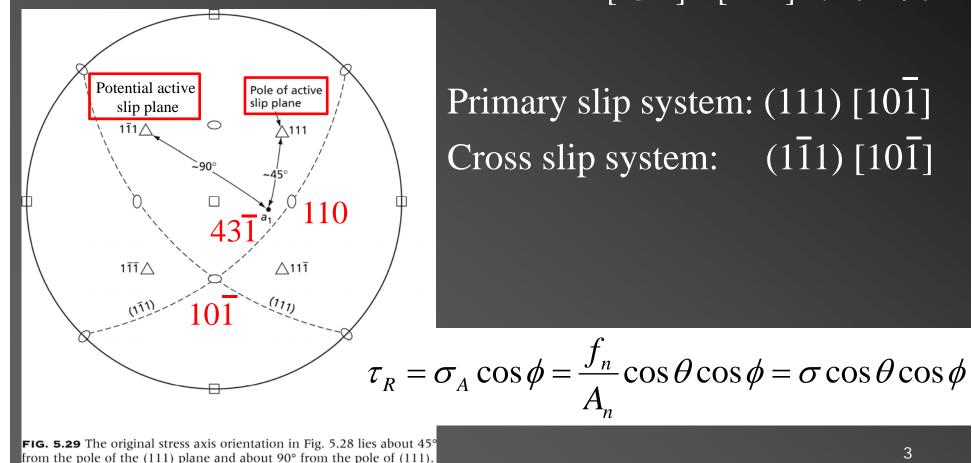


FIG. 5.14 A figure for the determination of the critical resolved shear stress equation

 $[43-1] \bullet [111] \Longrightarrow \theta \sim 47^{\circ}$ $[43-1] \bullet [1-11] \Rightarrow \theta \sim 90^{\circ}$

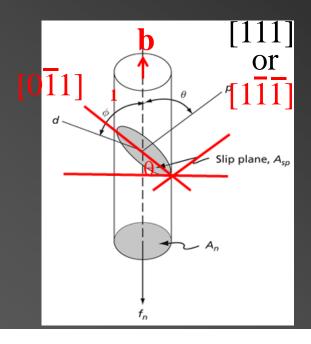
Primary slip system: (111) [101] Cross slip system: $(1\overline{1}1) [10\overline{1}]$

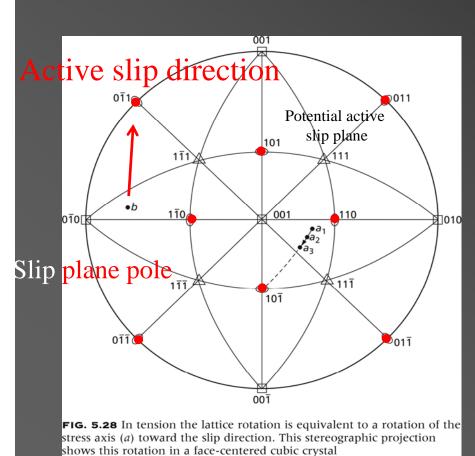


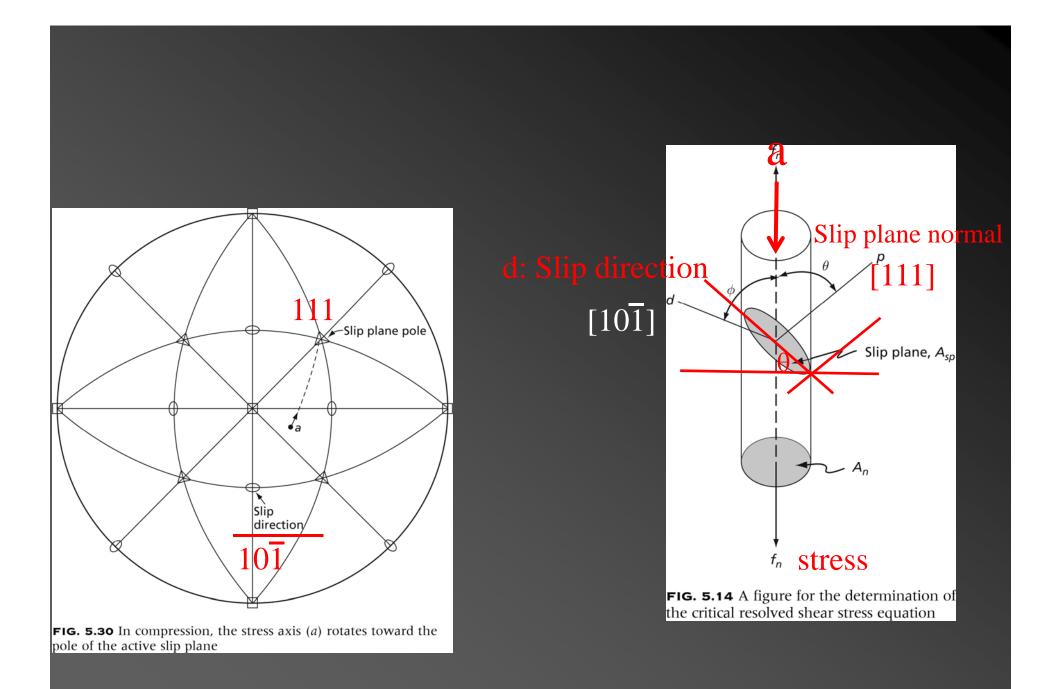
These are the two slip planes that contain the active slip direction

b [3-51] b • [1-1-1]; θ ~ 47° b • [111]; θ ~ 96°

Primary slip system: (111) [011] Cross slip system: (111) [011]







5.16 The Notation For The Slip Systems in The Deformation of FCC Crystals

Primary slip system: (111) [101]Cross slip system: (111) [101]

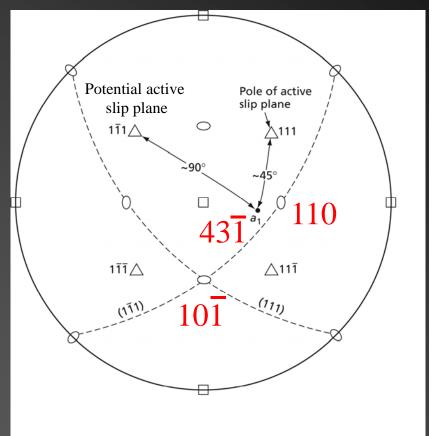
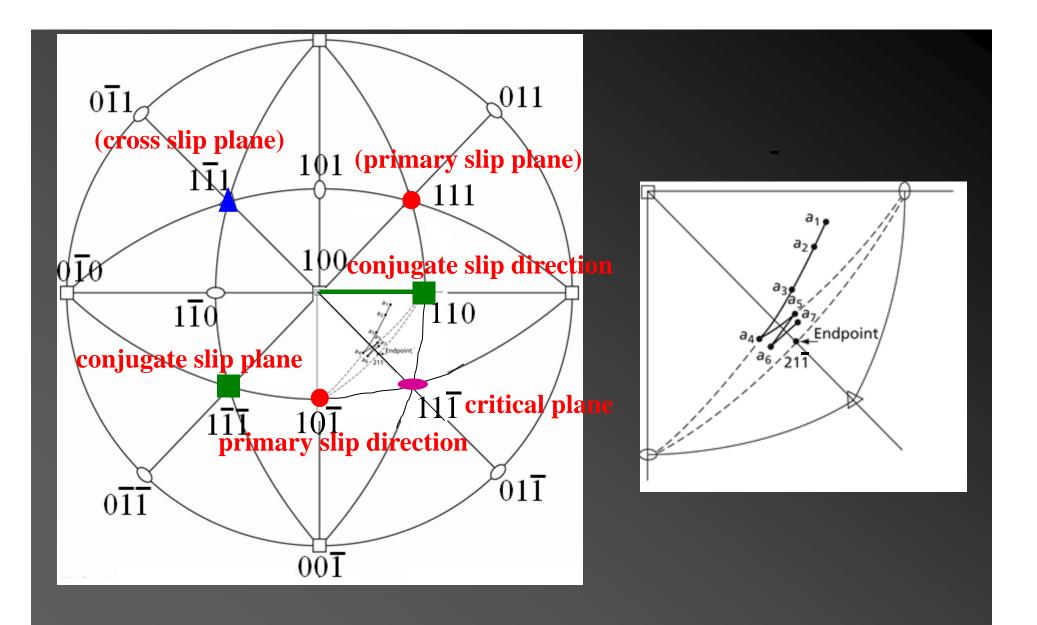
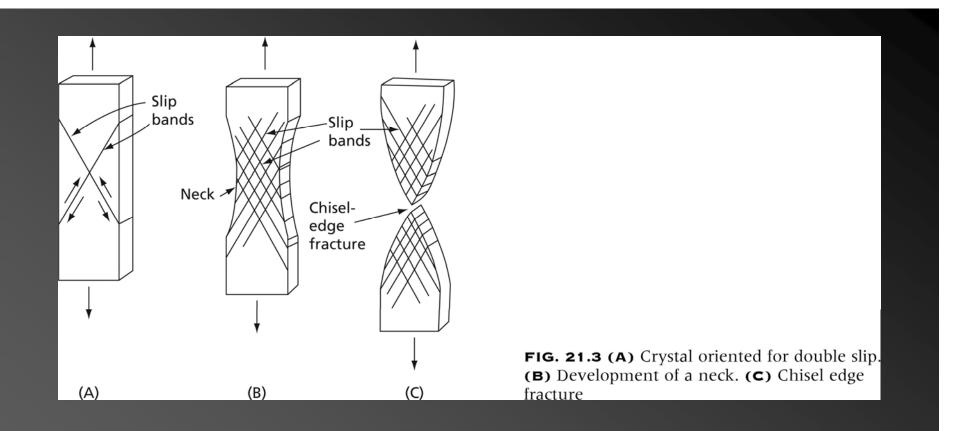


FIG. 5.29 The original stress axis orientation in Fig. 5.28 lies about 45° from the pole of the (111) plane and about 90° from the pole of (111). These are the two slip planes that contain the active slip direction



F. D. Rosi and C. H. Mathewson, Trans AIME, 188, 1159 (1950)

- Conjugate slip system: happen once the rotation of the crystal out of its original stereographic triangle into the one adjoining it.
 => resolved shear stress is greater on the (111)[110] slip system.
 ⇒ a₃ → a₄
- The crystal will continue to rotate with deformation occurring on alternating slip.



Ductility: FCC > HCP > cubic

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5.17 Work Hardening:

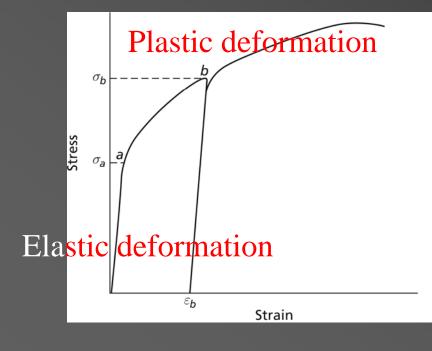
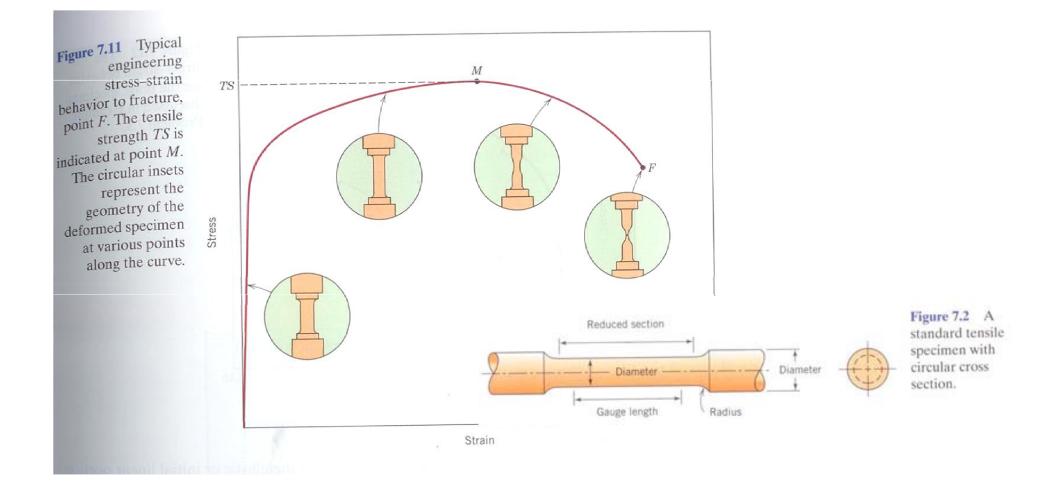
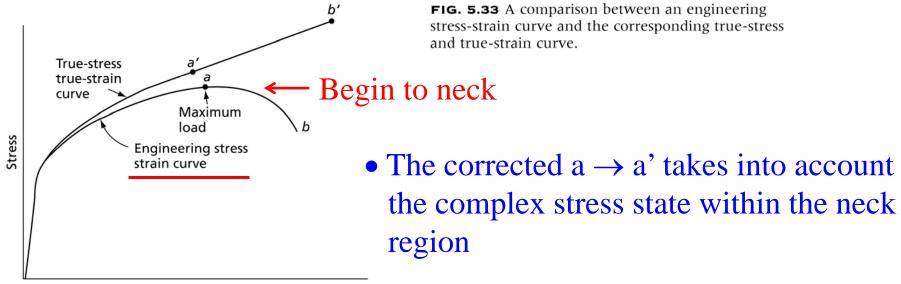


FIG. 5.32 Normally when a metal is deformed to a strain such as ϵ_b and then it is unloaded, it will not begin to deform until the stress is raised back to σ_b . The strain ϵ_b raises the flow stresses from σ_a to σ_b .

• Engineering stress and strain: expressed in terms of original sample dimension (A_0, l_0) . $\sigma_e = P/A_0$ (P: load); $\varepsilon_e = (l_i - l_0) / l_0 = \Delta l / l_0$



$$\sigma_{t} = P/A_{i}$$
 (P: load); $\varepsilon_{t} = \Delta l/l_{i}$ $(l_{i} = l_{0} + \Delta l)$



Strain

- A true stress and strain curve has less practical meaning for the engineering application.
 - \Rightarrow Because you have to keep tracking the size for each strain, and what the engineers care most is how strong the materials are and when they are going to fail.

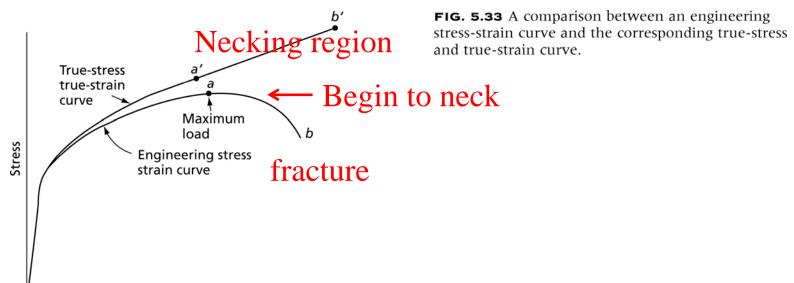
$$\sigma_{t} = P/A_{i}; \ \varepsilon_{t} = \Delta l/l_{i} \qquad \sigma_{e} = P/A_{0}; \ \varepsilon_{e} = \Delta l/l_{0}$$

$$\sigma_{t} = \frac{P}{A_{i}} = \frac{Pl_{i}}{A_{i}l_{i}} = \frac{Pl_{i}}{A_{0}l_{0}} = \frac{P}{A_{0}} \frac{l_{0} + \Delta l}{l_{0}} = \sigma_{e} \left(1 + \varepsilon_{e}\right) \qquad l_{i} = l_{0} + \Delta l$$

$$\sigma_{i}: \text{ true stress}; \qquad \sigma_{e}: \text{ engineering stress}; \\P: \text{ load} \qquad \varepsilon_{t}: \text{ true strain}; \\\varepsilon_{e}: \text{ engineering strain}; \\\Delta l: \text{ increase in length.}$$

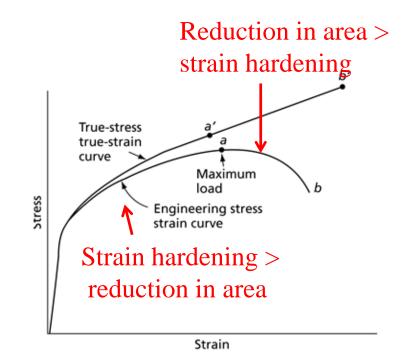
$$= \ln(1 + \varepsilon_{e})$$

fracture



Strain

5.18 Considere's Criterion



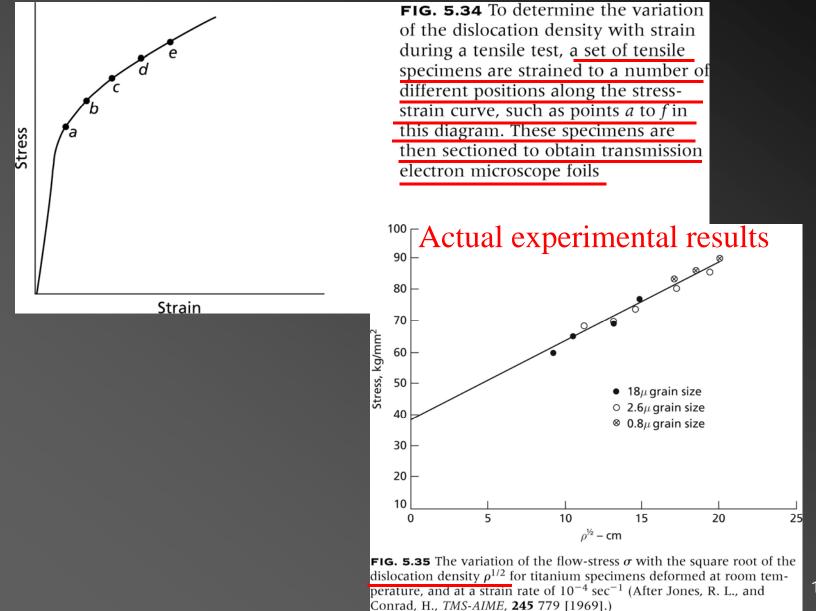
loading

$$P = \sigma_t A_i => dP = A_i d\sigma_t + \sigma_t dA_i = 0 => d\sigma_t = -\sigma_t \frac{dA_i}{A_i}$$

Strain hardening

$$dV = d(A_{i}l_{i}) = A_{i}dl_{i} + l_{i}dA_{i} = 0 \implies \frac{dA_{i}}{A_{i}} = -\frac{dl_{i}}{l_{i}} = -d\varepsilon_{t}$$
$$= > \sigma_{t} = -\frac{d\sigma_{t}}{\frac{dA_{i}}{A_{i}}} = \frac{d\sigma_{t}}{\frac{dl_{i}}{l_{i}}} = \frac{d\sigma_{t}}{d\varepsilon_{t}} = Considere's criterion$$

5.19 The Relation Between Dislocation Density And The Stress (Experimentally Observed)



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$$\sigma = \sigma_0 + k\rho^{1/2} \quad \begin{array}{l} \sigma: \text{ flow stress} \\ \rho: \text{ measured dislocation density} \\ \sigma_0: \text{ extrapolated to zero} \end{array}$$

$$\tau = \tau_0 + k\rho^{1/2} \qquad \begin{array}{l} \tau: \text{ flow stress} \\ \rho: \text{ measured dislocation density} \\ \tau_0: \text{ extrapolated to zero} \end{array}$$

• If ρ is zero, the metal could not be deformed. $\Rightarrow \sigma_0$ and τ_0 are best considered as convenient constants rather

than as simple physical properties.

5.20 Taylor's Relation

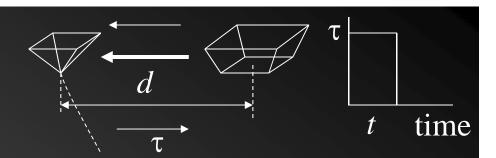
$$\tau = \mu \gamma = \mu b/(2\pi r) = \alpha \mu b/r$$

$$r \propto \rho^{-1/2}$$

$$\tau = \alpha \mu b / \rho^{-1/2} = \alpha \mu b \rho^{1/2} = k \rho^{1/2} \text{ where } k = \alpha \mu b$$

5.21 Dislocation velocity

• Dislocation velocity (v) v = d/t



1. From experimental data => Johnston and Gilman found $\ln v \propto \ln \tau$

power law: $v = (\tau/D)^m$

D: the stress yields at v = 1 cm s⁻¹; τ : applied shear stress m: exponent; function of purity, temp. etc.

2. Temperature dependence of v t_f: time of flight be tween obstacles => ln $v \propto 1/T$ (phonon effect)

3. Combine 1 & 2: single expression $v = f(\sigma) e^{-E/kT}$ 25°C > T > -50°C Stress Temperature dependence term dependence term

E: activation energy; $25^{\circ}C > T > -50^{\circ}C$ *k*: Boltzmann's constant

5.23 The Orowan Equation (Strain Rate)

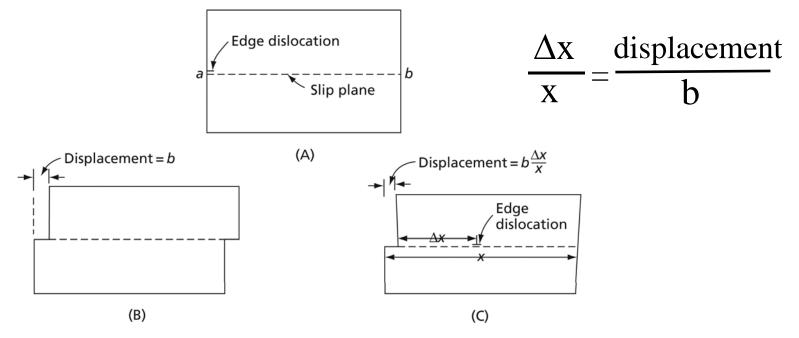


FIG. 5.36 The displacement of the two halves of a crystal is in proportion to the distance that the dislocation moves on its slip plane

• relation between the velocity (v) of the dislocations and the applied strain rate ($\dot{\varepsilon}$).

In (c): Shear by an amount =
$$\frac{b \Delta x}{x} = \frac{b \Delta A}{A}$$

 $\Delta \gamma \propto (b\Delta x/x)/x = \rho b\Delta x$ (because $(1/x^2) = \rho$)

 ρ : the dislocation density

$$\frac{\Delta \gamma}{\Delta t} = \dot{\gamma} = \frac{\rho b \Delta x}{\Delta t} = \rho b \overline{v}$$

Ė

Tensile strain rate:
$$\dot{\varepsilon} = \frac{1}{2}\dot{\gamma} = \frac{1}{2}\rho b\overline{v}$$

 \uparrow
Schmid orientation factor

5.22 The Discontinuous Nature of Dislocation Movement

In real crystal, there are a lot of obstacles in lattice
=> the movement of a dislocation is not smooth and continuous, but rather it occurs in steps.
=> Moves rapidly for a short distance; it stops and waits at an obstacle while eventually it passes; it moves rapidly again to the next obstacle.

